

Low voltage high performance NPN power transistor

Preliminary data

Features

- Very low collector-emitter saturation voltage
- High current gain characteristic
- Fast switching speed

Applications

- Emergency lighting
- LED
- Motherboard and hard disk drive
- Mobile equipment
- Battery charger
- Voltage regulation

Description

The device is a NPN transistor manufactured using new "PB-HCD" (power bipolar high current density) technology. The resulting transistor shows exceptional high gain performances coupled with very low saturation voltage.

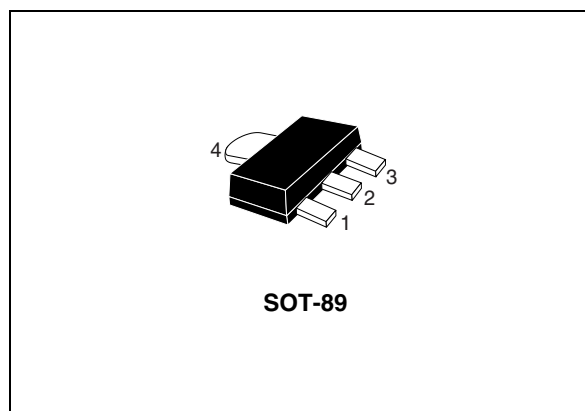


Figure 1. Internal schematic diagram

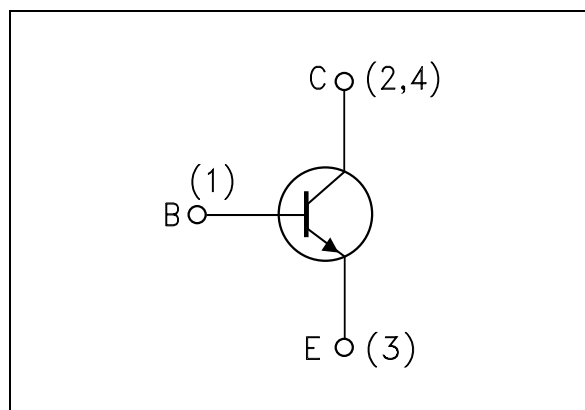


Table 1. Device summary

Order codes	Marking	Package	Packaging
2STF1525	1525	SOT-89	Tape and reel

1 Electrical ratings

Table 2. Absolute maximum rating

Symbol	Parameter	Value	Unit
V_{CEX}	Collector-emitter voltage ($V_{BE} = -1.5\text{ V}$)	95	V
V_{CEO}	Collector-emitter voltage ($I_B = 0$)	25	V
V_{EBO}	Emitter-base voltage ($I_C = 0$)	5	V
I_C	Collector current	5	A
I_{CM}	Collector peak current ($t_P < 5\text{ ms}$)	10	A
I_B	Base current	1	A
P_{TOT}	Total dissipation at $T_{amb} = 25\text{ °C}$	1.4	W
T_{stg}	Storage temperature	-65 to 150	°C
T_J	Max. operating junction temperature	150	°C

Table 3. Thermal data

Symbol	Parameter	Value	Unit
$R_{thJA}^{(1)}$	Thermal resistance junction-ambient max	89	°C/W

1. Device mounted on PCB area of 1 cm^2

2 Electrical characteristics

($T_{\text{case}} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

Table 4. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
I_{CBO}	Collector cut-off current ($I_{\text{E}} = 0$)	$V_{\text{CB}} = 50\text{ V}$			0.1	μA
I_{EBO}	Emitter cut-off current ($I_{\text{C}} = 0$)	$V_{\text{EB}} = 4\text{ V}$			0.1	μA
$V_{(\text{BR})\text{CEX}}$	Collector-emitter breakdown voltage ($V_{\text{BE}} = -1.5\text{ V}$)	$I_{\text{C}} = 1\text{ mA}$	95			V
$V_{(\text{BR})\text{CEO}}^{(1)}$	Collector-emitter breakdown voltage ($I_{\text{B}} = 0$)	$I_{\text{C}} = 10\text{ mA}$	25			V
$V_{(\text{BR})\text{EBO}}$	Emitter-base breakdown voltage ($I_{\text{C}} = 0$)	$I_{\text{E}} = 100\text{ }\mu\text{A}$	5			V
$h_{\text{FE}}^{(1)}$	DC current gain	$I_{\text{C}} = 0.5\text{ A}$ $V_{\text{CE}} = 2\text{ V}$ $I_{\text{C}} = 3\text{ A}$ $V_{\text{CE}} = 2\text{ V}$ $I_{\text{C}} = 5\text{ A}$ $V_{\text{CE}} = 5\text{ V}$	100	300 150		
$V_{\text{CE(sat)}}^{(1)}$	Collector-emitter saturation voltage	$I_{\text{C}} = 3\text{ A}$ $I_{\text{B}} = 300\text{ mA}$ $I_{\text{C}} = 3.5\text{ A}$ $I_{\text{B}} = 40\text{ mA}$		220	500	mV mV
$V_{\text{BE(sat)}}^{(1)}$	Base-emitter saturation voltage	$I_{\text{C}} = 3\text{ A}$ $I_{\text{B}} = 300\text{ mA}$			1.2	V
C_{CBO}	Collector-base capacitance ($I_{\text{E}} = 0$)	$V_{\text{CB}} = 10\text{ V}$, $f = 1\text{ MHz}$		20		pF
f_{T}	Transition frequency	$V_{\text{CE}} = 10\text{ V}$ $I_{\text{C}} = 50\text{ mA}$		120		MHz
t_{on} t_{off}	Resistive load Turn-on time Turn-off time	$I_{\text{C}} = 1.5\text{ A}$ $V_{\text{CC}} = 10\text{ V}$ $I_{\text{B1}} = -I_{\text{B2}} = 150\text{ mA}$		90 700		ns ns

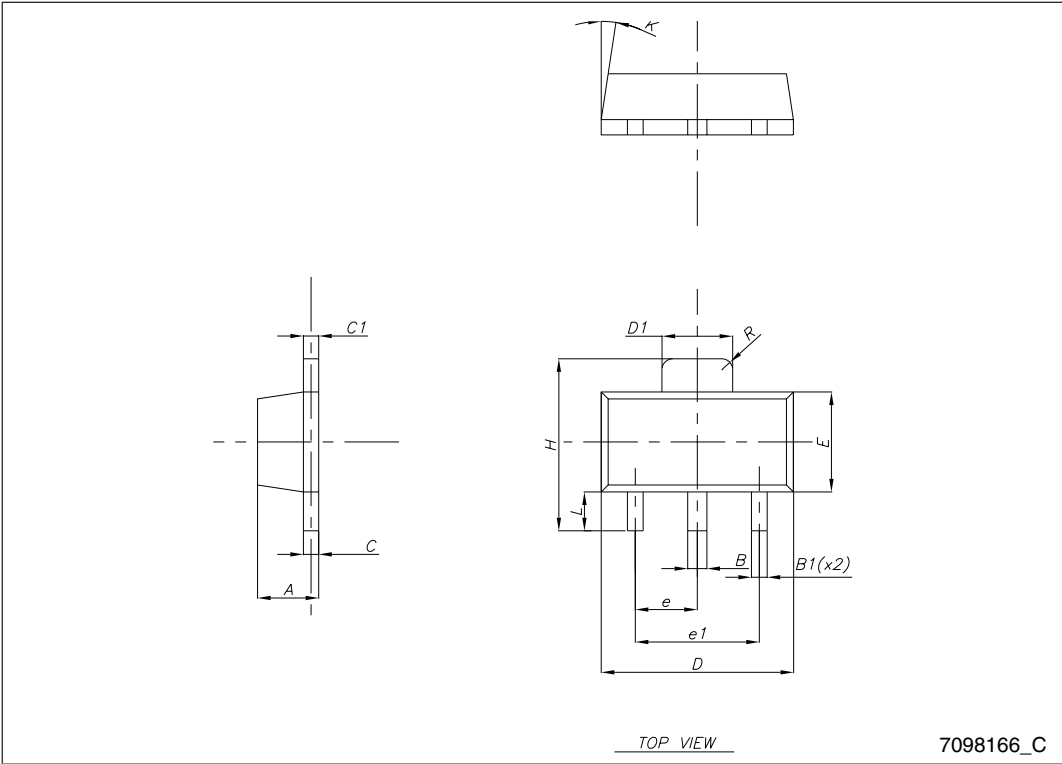
1. Pulsed duration = 300 μs , duty cycle $\leq 1.5\%$

3 Package mechanical data

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SOT-89 mechanical data

Dim.	mm		
	Min.	Typ.	Max.
A	1.40		1.60
B	0.44		0.56
B1	0.36		0.48
C	0.35		0.44
C1	0.35		0.44
D	4.40		4.60
D1	1.62		1.83
E	2.29		2.60
e	1.42		1.57
e1	2.92		3.07
H	3.94		4.25
K	1°		8°
L	0.89		1.20
R		0.25	



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Revision history

Table 5. Document revision history

Date	Revision	Changes
04-Jun-2009	1	Initial release.

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